Department of Physics

Study of oxide thin films and heterostructures

The research in my group started with the pursuit of room-temperature diluted magnetic semiconductor based on zin oxide (ZnO) and rare earth elements, and it broadened to study the interplay of different properties of oxide thin films, e.g., semiconducting, magnetism, etc., in hetero-junctions, multilayer heterostructures. We are looking into the effects and mechanism for oxide electronic and spintronic applications.

Techniques used in study

Pulsed-laser deposition, x-ray diffraction, Raman-scattering spectroscopy, atomic force microscopy, photoluminescence spectroscopy, optical transmission spectroscopy, spectroscopic ellipsometry, SQUID magnetometry, spectroscopic magneto-optical Faraday effect, I-V and Hall effect measurement

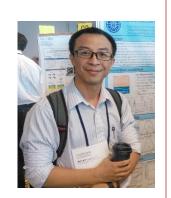
Fang-Yuh Lo, Associate Professor Department of Physics fangyuhlo@ntnu.edu.tw

Background:

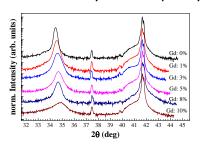
Dr. rer. nat., Fakultät für Physik und Astronomie, Ruhr-Universität Bochum, Germany

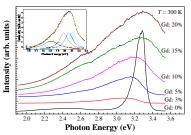
Funding:

Ministry of Science and Technology Ministry of Education National Taiwan Normal University

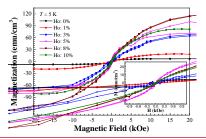


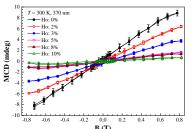
Thin film crystalline quality and defect identification





Magnetism and magneto-optical effect





Publications

- Paramagnetic dysprosium-doped zinc oxide thin films grown by pulsed-laser deposition, <u>Fang-Yuh Lo*</u>, Yi-Chieh Ting, Kai-Chieh Chou, Tsung-Chun Hsieh, Cin-Wei Ye, Yung-Yuan Hsu, Ming-Yau Chern and Hsiang-Lin Liu, J. Appl. Phys. <u>117</u>, 213911 (2015).
- Voltage induced reversible and irreversible change of magnetic coercivity in Co/ZnO heterostructure, Chuan-Che Hsu, Po-Chun Chang, Venkata Ramana Mudinepalli, Tsung-Chun Hsieh, <u>Fang-Yuh Lo*</u>, and Wen-Chin Lin*, J. Appl. Phys. 119, 093905 (2016).